

Schottky Diode

DSA30C45PB

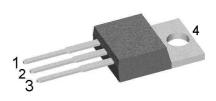
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V _{RRM}	=	45 V
I _{FAV}	<i>=</i> 2x	15 A
V_	=	0.63 V

High Performance Schottky Diode Low Loss and Soft Recovery Common Cathode

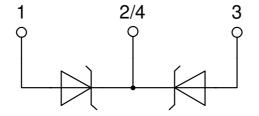
Part number

DSA30C45PB



Backside: cathode

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Features / Advantages:

- Very low Vf
- Extremely low switching losses
- Low Irm values
- Improved thermal behaviour
- High reliability circuit operation
 Low voltage peaks for reduced
- protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: TO-220

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

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Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.

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Schottky	/				Rating	S	
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse block	ng voltage	$T_{VJ} = 25^{\circ}C$			45	V
V _{RRM}	max. repetitive reverse blocking v	oltage	$T_{VJ} = 25^{\circ}C$			45	V
l _R	reverse current, drain current	$V_{R} = 45 V$	$T_{VJ} = 25^{\circ}C$			250	μA
		$V_{R} = 45 V$	$T_{vJ} = 125^{\circ}C$			2.5	mA
V _F	forward voltage drop	I _F = 15 A	$T_{vJ} = 25^{\circ}C$			0.75	V
		$I_{F} = 30 \text{ A}$				0.91	V
		I _F = 15 A	T _{vJ} = 125°C			0.63	V
		$I_{F} = 30 \text{ A}$				0.79	V
I FAV	average forward current	T _c = 155°C	T _{vJ} = 175°C			15	A
		rectangular d = 0.5					
V _{F0}	threshold voltage		T _{vJ} = 175°C			0.42	V
r _F	slope resistance } for power lo	oss calculation only				9.9	mΩ
R _{thJC}	thermal resistance junction to cas	е				1.75	K/W
R _{thCH}	thermal resistance case to heatsir	nk			0.5		K/W
P _{tot}	total power dissipation		$T_c = 25^{\circ}C$			85	W
	max. forward surge current	t = 10 ms; (50 Hz), sine; $V_{R} = 0 V$	$T_{vJ} = 45^{\circ}C$			340	A
CJ	junction capacitance	$V_{B} = 5V f = 1 MHz$	$T_{VJ} = 25^{\circ}C$		497		pF

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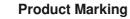
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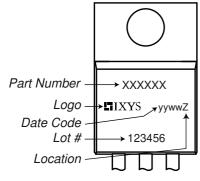


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Package TO-220				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
	RMS current	per terminal n			35	Α	
T _{vj}	virtual junction temperature		-55		175	°C	
T _{op}	operation temperature		-55		150	°C	
T _{stg}	storage temperature		-55		150	°C	
Weight				2		g	
M _D	mounting torque		0.4		0.6	Nm	
F _c	mounting force with clip		20		60	Ν	





Part description

- D = Diode
- S = Schottky Diode A = low VF
- 30 = Current Rating [A]
- C = Common Cathode
- 45 = Reverse Voltage [V]
- PB = TO-220AB (3)

[Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
	Standard	DSA30C45PB	DSA30C45PB	Tube	50	503934

Similar Part	Package	Voltage class
DSA30C45PC	TO-263AB (D2Pak) (2)	45
DSA30C45HB	TO-247AD (3)	45

Equiva	lent Circuits for	Simulation	* on die level	$T_{vJ} = 175^{\circ}C$
)[R₀_]-	Schottky		
V _{0 max}	threshold voltage	0.42		V
$\mathbf{R}_{0 \max}$	slope resistance *	6.7		mΩ

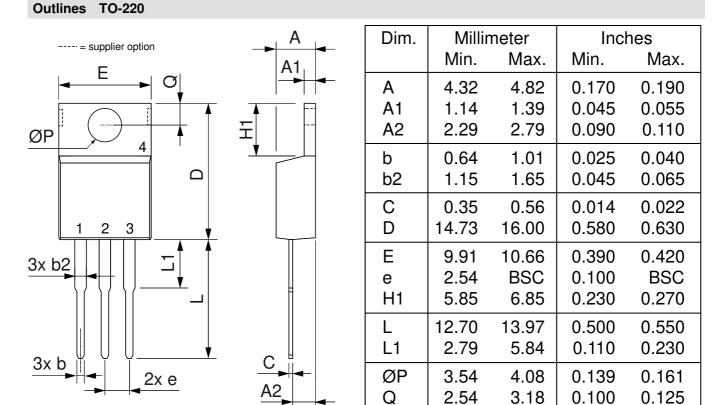
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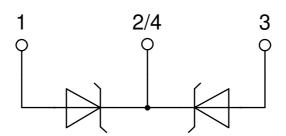
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